NSN 5961-00-137-7204

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-137-7204 **Inclosure Material:** Ceramic **Overall Length:** 0.260 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.370 inches **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 40.0 collector to emitter voltage/static/base open all transistor and 65.0 collector to base voltage, dc all transistor and 6.0 emitter to base voltage, dc all transistor **Current Rating Per Characteristic:** 1.00 amperes source cutoff current all transistor **Power Rating Per Characteristic:** 600.0 milliwatts small-signal input power, common-collector preset all transistor **Transfer Ratio:** 150.0 static forward current transfer ratio, common-emitter all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

No

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Demilitarization: